

Technical Data
Data Sheet N1221, Rev. B

Green Products

322CNQ030 SCHOTTKY RECTIFIER

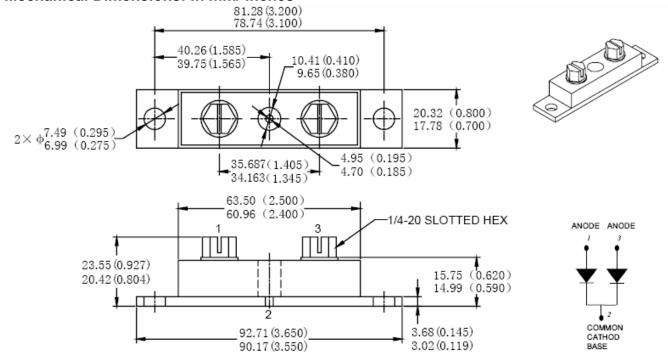
Applications:

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

Features:

- 150 ℃ T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/ Inches



PRM4 (Non-Isolated)

MARKING, MOLDING RESIN

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	V_{RWM}	-	30		V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =100°C,	150 per leg 300 per device		Α
Current	, ,	rectangular wave form			
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	1800		А
Non-Repetitive Avalanche Energy(peg leg)	E _{AS}	T_J =25 °C , I_{AS} =1A,L=30mH	270		mJ
Repetitive Avalanche Current(peg leg)	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A =1.5 \times V_R typical		60	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	@ 150A, Pulse, T_J = 25 °C@ 300A, Pulse, T_J = 25 °C	0.56 0.70	V
	V_{F2}	@ 150A, Pulse, T _J = 125 °C @ 300A, Pulse, T _J = 125 °C	0.49 0.68	V
Max. Reverse Current (per leg) *	I _{R1}	@V _R = rated V _R T _J = 25 °C	10	mA
	I_{R2}	$@V_R = \text{rated } V_R T_J = 125 ^{\circ}\text{C}$	650	mA
Max. Junction Capacitance (per leg)	C_{T}	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	11000	pF
Typical Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

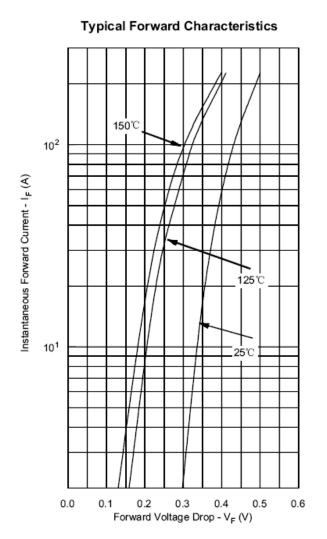
^{*} Pulse Width < 300µs, Duty Cycle <2%

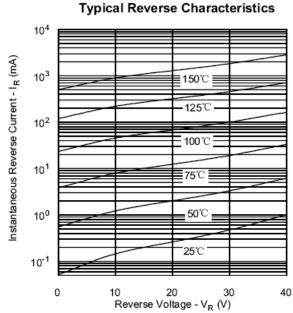
Thermal-Mechanical Specifications:

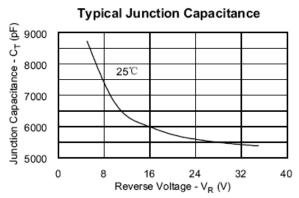
Characteristics	Symbol	Condition	Specifi	Units		
Max. Junction Temperature	T _J	-	-55 to	°C		
Max. Storage Temperature	T _{stg}	-	-55 to	°C		
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ heta JC}$	DC operation	0.50		°C/W	
Maximum Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.25		°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{\theta cs}$	Mounting surface, smooth and greased	0.10		°C/W	
Mounting Torque	Тм	-	Mounting Torque Terminal Torque	24(min) 35(max) 35(min) 46(max)	Kg-cm	
Approximate Weight	wt	-	79		g	
Case Style	PRM4 Non-Isolated					

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